

# NSVBC114EPDXV6T1G

# NSVBC114EPDXV6T1G Information



For Reference Only

Part Number	NSVBC114EPDXV6T1G	
Manufacturer	ON Semiconductor	
Category	Discrete Semiconductor Products Transistors - Bipolar (BJT) - Arrays, Pre-Biased	
Description	TRANS NPN/PNP BIAS SOT563	
Package	SOT-563, SOT-666	
	For the pricing/inventory/lead time, please contact us Website: https://www.heisener.com E-mail: salesdept@heisener.com	



Request a Quote

# **Certified Quality**

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



# NSVBC114EPDXV6T1G Specifications

	Report errors?
Supplier Device Package	SOT-563
Package / Case	SOT-563, SOT-666
Mounting Type	Surface Mount
Power - Max	500mW
Frequency - Transition	-
Current - Collector Cutoff (Max)	500nA
Vce Saturation (Max) @ Ib, Ic	250mV @ 300µA, 10mA
DC Current Gain (hFE) (Min) @ Ic, Vce	35 @ 5mA, 10V
Resistor - Emitter Base (R2) (Ohms)	10k
Resistor - Base (R1) (Ohms)	10k
Voltage - Collector Emitter Breakdown (Max)	50V
Current - Collector (Ic) (Max)	100mA
Transistor Type	1 NPN, 1 PNP - Pre-Biased (Dual)
Series	-
Package	SOT-563, SOT-666
	Transistors - Bipolar (BJT) - Arrays, Pre-Biased
Category	Discrete Semiconductor Products
Manufacturer	ON Semiconductor
Manufacturer Part Number	NSVBC114EPDXV6T1G

## NSVBC114EPDXV6T1G Guarantees



**Quality Guarantees** 

We provide 90 days warranty. \* If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



#### Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

## NSVBC114EPDXV6T1G Payment Methods



If you have any question about NSVBC114EPDXV6T1G, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com